

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IPW50R199CP

IIPW50R199CP

• FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \leqslant 199m_{\Omega}$
- · Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

High Peak Current Capability

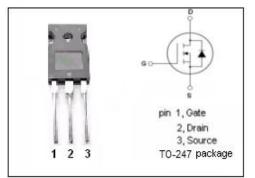
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

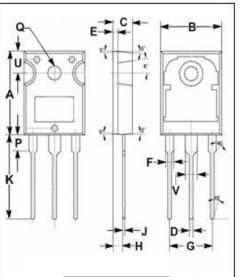
SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	500	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	17	А
I _{DM}	Drain Current-Single Pulsed 40		A
PD	Total Dissipation @T₀=25℃	139	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

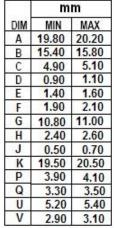
• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.9	°C /W
Rth(j-a)	Channel-to-ambient thermal resistance	62	°C/W

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	500			V
$V_{GS(th)}$	Gate Threshold Voltage	VDS=VGS; I₀=660 µ A	2.5		3.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	V _{GS} =10V; I _D =9.9A			0.199	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = 20V; V _{DS} = 0V			0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =500V; V _{GS} = 0V			1	μA
V _{SD}	Diode forward voltage	I _F =9.9A, V _{GS} = 0V			1.2	V

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